Unitized Semiconductor Devices - Page 1 of 1



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Metal	aterial:
	ath.
Overall Len 0.185 inches	-
Terminal Le	
0.500 inches	
Overall Diar	
0.370 inches	
	onic Device Engineering Council/jedec/case Outline Designation:
To-78	one Device Engineering Council/jedec/case Outline Designation.
	Nome And Quantity
2 transistor	Name And Quantity:
	athody
Mounting M Terminal	Guiva.
	rcle Diameter:
0.200 inches	
Features Pr	
	sealed case
-	ctor Material:
Silicon all tra	
	ing In Volts Per Characteristic:
	own voltage, collector-to-base, emitter open all transistor
	ing Per Characteristic:
	nperes source cutoff current all transistor
	ng Per Characteristic:
	nall-signal input power, common-collector preset all transistor
Transfer Ra	
	brward current transfer ratio, common-emitter all transistor
Special Fea	
-	junction pattern arrangement: npn
	pe And Quantity:
8 uninsulate	
Shelf Life:	
N/a	
Unit Of Mea	sure:
Demilitariza	tion:
No	
Fiig:	
A110a0	